

TinyLogic UHS Unbuffered Inverter

NC7SZU04

Description

The NC7SZU04 is a single unbuffered inverter from **onsemi**'s Ultra–High Speed series of TinyLogic. The special purpose unbuffered circuit design is primarily intended for crystal oscillator or analog applications. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a broad $V_{\rm CC}$ operating range. The device is specified to operate over the 1.65 V to 5.5 V $V_{\rm CC}$ range.

Features

- Unbuffered for Crystal Oscillator and Analog Applications
- Balanced Output Drive: ±32 mA at 4.5 V V_{CC}
- Balanced Output Drive: ±16 mA at 4.5 V V_{CC} (NC7SZU04P5X-L22057)
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Matches Performance of LCX Operated at 3.3 V V_{CC}
- Low Quiescent Power: $I_{CC} < 2 \mu A$, $V_{CC} = 5.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- Ultra-Small MicroPakTM Packages
- Space–Saving SOT–23–5 and SC–88A Packages
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

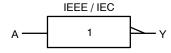
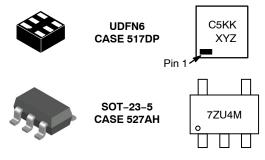


Figure 1. Logic Symbol

1

MARKING DIAGRAMS







C5, 7ZU4, ZU4 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code
XY = 2-Digit Date Code Format
Z = Assembly Plant Code
M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 7 of this data sheet.

Pin Configurations

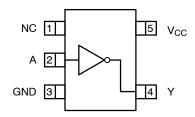


Figure 2. SC88A and SOT-23-5 (Top View)

NC 1 6 V_{CC} A 2 5 NC GND 3 4 Y

Figure 3. MicroPak (Top Through View)

PIN DEFINITIONS

Pin # SC-88A / SOT-23-5	Pin # MicroPak	Name	Description
1	1, 5	NC	No Connect
2	2	Α	Input
3	3	GND	Ground
4	4	Υ	Output
5	6	V _{CC}	Supply Voltage

FUNCTION TABLE

Inputs	Output
Α	Y
L	Н
Н	L

H = HIGH Logic Level L = LOW Logic Level

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
lok	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
		V _{OUT} > V _{CC}	-	+50	
I _{OUT}	DC Output Current		-	±50	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current		-	±50	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bia	S	-	+150	°C
TL	Junction Lead Temperature (Solo	dering, 10 Seconds)	-	+260	°C
P_{D}	Power Dissipation in Still Air	SOT-23-5	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	
		MicroPak2™-6	-	812	
ESD	Human Body Model, JEDEC: JESD22-A114		-	4000	V
	Charge Device Model, JEDEC: J	JESD22-C101	-	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.50	5.5	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
$\theta_{\sf JA}$	Thermal Resistance	SOT-23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	
		MicroPak2-6	_	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTRICAL CHARACTERISTICS

				T,	T _A = +25°C		T _A = -40	to +85°C	
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
V_{IH}	HIGH Level Input		1.8 to 2.7	0.85 V _{CC}	_	-	0.85 V _{CC}	_	٧
	Voltage		3.0 to 5.5	0.80 V _{CC}	-	-	0.80 V _{CC}	_	
V_{IL}	LOW Level Input		1.8 to 2.7	-	-	0.15 V _{CC}	_	0.15 V _{CC}	V
	Voltage		3.0 to 5.5	-	-	0.20 V _{CC}	_	0.20 V _{CC}	
V _{OH}	High-Level Output Voltage	$\begin{split} &V_{IN} = \text{GND} \\ &I_{OH} = -100 \ \mu\text{A} \\ &I_{OH} = -4 \ \text{mA} \\ &I_{OH} = -8 \ \text{mA} \\ &I_{OH} = -12 \ \text{mA} \\ &I_{OH} = -16 \ \text{mA} \\ &I_{OH} = -24 \ \text{mA} \\ &I_{OH} = -32 \ \text{mA} \end{split}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	V _{CC} - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	V _{CC} 1.4 2.1 2.4 2.7 2.5 4.0	- - - - -	V _{CC} - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	- - - - -	V
VoL	Low-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{CC} \\ &I_{OL} = 100 \; \mu A \\ &I_{OL} = 4 \; mA \\ &I_{OL} = 8 \; mA \\ &I_{OL} = 12 \; mA \\ &I_{OL} = 16 \; mA \\ &I_{OL} = 24 \; mA \\ &I_{OL} = 32 \; mA \end{aligned}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	- - - - -	- 0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55	- - - - -	0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V, GND	1.65 to 5.5	-	_	±1	-	±10	μΑ
I _{CC}	Quiescent Supply Current	V _{IN} = 5.5 V, GND	1.65 to 5.5	-	-	2	-	20	μΑ
I _{CCPEAK}	Peak Supply	V _{OUT} = Open, V _{IN} = Adjust	1.8	-	2	-	-	-	mA
	Current in Analog Operation	for Peak I _{CC} Current	2.5	_	4	_	_	_	
			3.3	_	10	_	_	_	
			5.0	-	30	-	-	-	

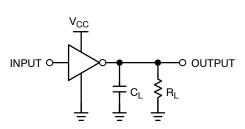
DC ELECTRICAL CHARACTERISTICS (NC7SZU04P5X-L22057, NC7SZU04L6X-L22175, NC7SZU04FHX-L22175)

					T,	ղ = +25°	C	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Con	ditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input	1.8 to 2.7			0.85 V _{CC}	_	_	0.85 V _{CC}	-	V
	Voltage	3.0 to 5.5			0.80 V _{CC}	_	-	0.80 V _{CC}	-	1
V _{IL}	LOW Level Input	1.8 to 2.7			_	_	0.15 V _{CC}	_	0.15 V _{CC}	V
	Voltage	3.0 to 5.5			_	_	0.20 V _{CC}	_	0.20 V _{CC}	1
V _{OH}	HIGH Level	1.65	$V_{IN} = V_{IL}, I_O$	H = -100 μA	1.55	1.65	_	1.55	-	V
	Output Voltage	1.80			1.60	1.80	-	1.60	-	
		2.30			2.10	2.30	-	2.10	-	1
		3.00			2.70	3.00	_	2.70	-	1
		4.50			4.00	4.40	-	4.00	-	
		1.65	V _{IN} = GND	$I_{OH} = -4 \text{ mA}$	1.29	1.52	_	1.29	-	
		2.30		$I_{OH} = -4 \text{ mA}$	1.90	2.14	_	1.90	-	
		3.00		I _{OH} = -8 mA	2.40	2.75	_	2.40	-	
		3.00		I _{OH} = -12 mA	2.30	2.61	_	2.30	-	
		4.50		I _{OH} = -16 mA	3.80	4.13	_	3.80	-	
V _{OL}	LOW Level	1.65	$V_{IN} = V_{IH}$, $I_{OL} = 100 \mu A$		-	0.00	0.10	_	0.10	V
	Output Voltage	1.80			_	0.00	0.20	_	0.20	
		2.30			_	0.00	0.20	_	0.20	
		3.00			_	0.00	0.30	_	0.30	
		4.50			_	0.00	0.50	_	0.50	
		1.65	V _{IN} = V _{CC}	I _{OL} = 4 mA	-	0.80	0.24	_	0.24	
		2.30		I _{OL} = 4 mA	_	0.10	0.30	_	0.30	1
		3.00		I _{OL} = 8 mA	_	0.17	0.40	_	0.40	1
		3.00		I _{OL} = 12 mA	_	0.25	0.55	_	0.55	1
		4.50		I _{OL} = 16 mA	_	0.226	0.55	_	0.55	
I _{IN}	Input Leakage Current	1.65 to 5.5	$V_{IN} = 5.5 V,$	GND	-	-	±1	-	±10	μΑ
I _{CC}	Quiescent Supply Current	1.65 to 5.50	V _{IN} = 5.5 V,	GND	-	-	2	-	20	μΑ
I _{CCPEAK}	Peak Supply	1.8	V _{OUT} = Ope	n, V _{IN} = Adjust	_	2	-	-	-	mA
	Current in Analog Operation	2.5	for Peak I _{CC}	Current	_	4	-	-	-	1
		3.3	1		_	10	-	-	-	1
		5.0	1		_	30	-	-	_	1

AC ELECTRICAL CHARACTERISTICS

				٦	Γ _A = +25°C	;	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay	1.65	C _L = 15 pF,	-	_	11.7	-	12.1	ns
	(Figure 4, 5)	1.80	$R_L = 1 M\Omega$	-	-	8.5	-	9.0	
		2.50 ±0.20		-	-	6.2	-	6.5	
		3.30 ±0.30		-	-	4.5	-	4.8	
		5.00 ±0.50		-	-	3.9	-	4.1	
		3.30 ±0.30	C _L = 50 pF,	_	_	6.0	-	6.5	
		5.00 ±0.50	$R_L = 500 \Omega$	-	_	5.0	-	5.5	
C _{IN}	Input Capacitance	0.00		-	4.5	-	-	_	pF
C _{PD}	Power Dissipation Capacitance	3.30		-	6.3	-	-	_	pF
(Note 2) (Figure 6)	5.00		-	9.5	-	-	-		

 C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: $I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).$



NOTE:

- 3. C_L includes load and stray capacitance. 4. Input PRR = 1.0 MHz; t_W = 500 ns

Figure 4. AC Test Circuit

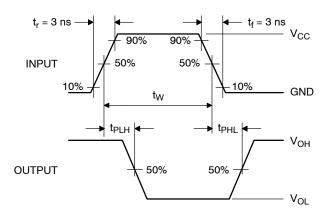
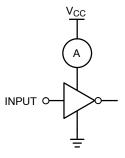


Figure 5. AC Waveforms



NOTE:

- 5. When operating the NC7SZU04's unbuffered output stage in its linear range, as in oscillator applications, care must be taken to observe maximum power rating for the device and package. The high drive nature of the design of the output stage results in substantial simultaneous conduction currents when the stage is in the linear region. See the I_{CCPEAK} specification in the <u>DC Electrical Characteristics</u> table.
- 6. Input = AC Waveform; $t_r = t_f = 1.8$ ns; PRR = Variable; Duty Cycle = 50%.

Figure 6. I_{CCD} Test Circuit

ORDERING INFORMATION

Part Number	Top Mark	Packages	Shipping [†]
NC7SZU04M5X	7ZU4	SOT-23-5	3000 / Tape & Reel
NC7SZU04M5X-L22090	7ZU4	SOT-23-5	3000 / Tape & Reel
NC7SZU04P5X	ZU4	SC-88A	3000 / Tape & Reel
NC7SZU04P5X-L22057	ZU4	SC-88A	3000 / Tape & Reel
NC7SZU04L6X	C5	SIP6, MicroPak	5000 / Tape & Reel
NC7SZU04L6X-L22175	C5	SIP6, MicroPak	5000 / Tape & Reel
NC7SZU04FHX	C5	UDFN6, MicroPak2	5000 / Tape & Reel
NC7SZU04FHX-L22175	C5	UDFN6, MicroPak2	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



DATE 31 AUG 2016



NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
 4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

 - OTHER LINE IN THE MARK CODE LAYOUT.

DOCUMENT NUMBER:	98AON13590G	Electronic versions are uncontrolled except when accessed directly from the Document F Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SIP6 1.45X1.0		PAGE 1 OF 1		

ON Semiconductor and un are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE L**

DATE 17 JAN 2013



- TES:
 DIMENSIONING AND TOLERANCING
 PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 419A-01 OBSOLETE. NEW STANDARD 3.
- 419A-02.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008 REF		0.20	REF	
S	0.079	0.087	2.00	2.20	

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



0.50 0.0197 0.65 0.025 0.65 0.025 0.40 0.0157 1.9 mm 0.0748 SCALE 20:1

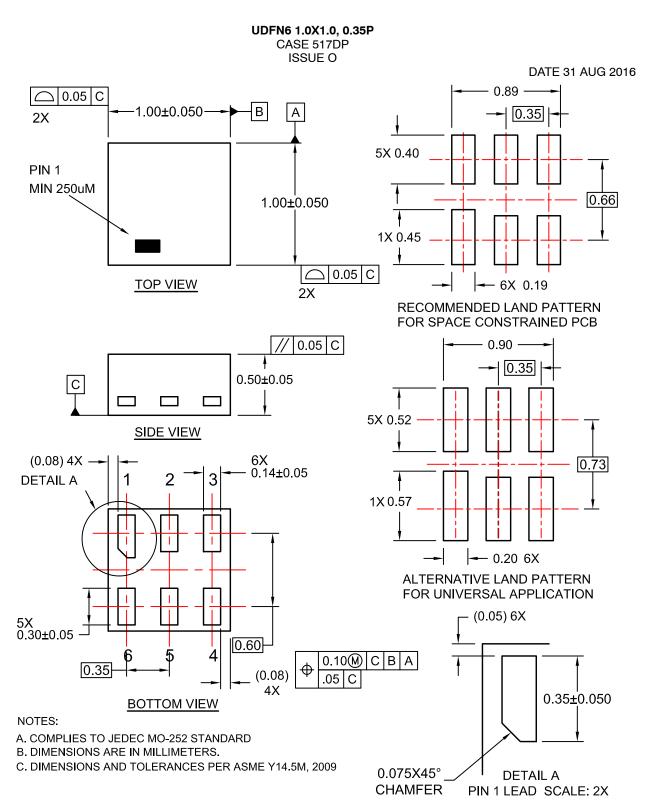
SOLDER FOOTPRINT

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

5. COLLECTOR	5. CATHODE	5. CATHODE I	5. GATE 2	5. CATHODE 4
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE 1	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:	98ASB42984B	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SC-88A (SC-70-5/SOT-353)		PAGE 1 OF 1

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



DOCUMENT NUMBER:	98AON13593G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	UDFN6 1.0X1.0, 0.35P		PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



REFERENCE



A

F1 F

В

DATE 09 JUN 2021

NUTES

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894

DIM

- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS, MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.

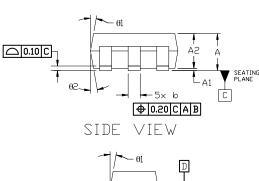
MIN.

DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL BE O. 08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.

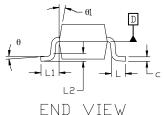
MILLIMETERS

ИПМ.

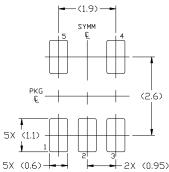
MAX.



TOP VIEW



Α 0.90 1.45 A1 0.00 0.15 Α2 0.90 1.15 1.30 b 0.30 0.50 0.08 0.22 n 2.90 BSC 2.80 BSC E1 1.60 BSC 0.95 BSC е 0.45 0.30 0.60 L1 0.60 REF 0.25 REF L2 4° θ 0° 10° 15° θ1 0° 10° θ2 15°



GENERIC MARKING DIAGRAM*



XXX = Specific Device Code = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the $\square N$ Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON34320E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT-23, 5 LEAD		PAGE 1 OF 1

ON Semiconductor and unare trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative